

SLLS854-AUGUST 2007

FEATURES

- Operates With 3-V to 5.5-V V_{CC} Supply
- · Operates up to 1 Mbit/s
- Low Standby Current . . . 1 μA Typical
- External Capacitors . . . 4 × 0.1 μF
- Accepts 5-V Logic Input With 3.3-V Supply
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using Human-Body Model (HBM)

APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

DB, DW, OR PW PACKAGE (TOP VIEW) 20 FORCEOFF EΝ[C1+[]2 19 V_{CC} V+**∏** 3 18 **∏** GND C1−∏4 17 DOUT1 C2+ $\prod 5$ 16**∏** RIN1 15 ROUT1 C2−∏6 V-**∏** 7 14 | FORCEON DOUT2 18 13 DIN1 12 DIN2 RIN2 ¶ 9 11 NINVALID ROUT2 10

DESCRIPTION/ORDERING INFORMATION

The TRSF3223 consists of two line drivers, two line receivers, and a dual charge-pump circuit with ± 15 -kV ESD protection pin to pin (serial-port connection pins, including GND). The device provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The device operates at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/ μ s to 150 V/ μ s.

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and $\overline{FORCEOFF}$ is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If $\overline{FORCEOFF}$ is set low and enable (\overline{EN}) is high, both drivers and receivers are shut off, and the supply current is reduced to 1 μA . Disconnecting the serial port or turning off the peripheral drivers causes auto-powerdown to occur. Auto-powerdown can be disabled when FORCEON and $\overline{FORCEOFF}$ are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The $\overline{INVALID}$ output is used to notify the user if an RS-232 signal is present at any receiver input. $\overline{INVALID}$ is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V or has been between -0.3 V and 0.3 V for less than 30 μs . $\overline{INVALID}$ is low (invalid data) if the receiver input voltage is between -0.3 V and 0.3 V for more than 30 μs . Refer to Figure 4 for receiver input levels.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ORDERING INFORMATION

T _A	PACKAGE	(1)(2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube of 25	TRSF3223CDW	TRSF3223C
	SOIC - DW	Reel of 2000	TRSF3223CDWR	183532230
0°C to 70°C	SSOP – DB	Tube of 70	TRSF3223CDB	RT23C
0-0 10 70-0	220b – DB	Reel of 2000	TRSF3223CDBR	RIZSC
	TSSOP – PW	Tube of 70	TRSF3223CPW	RT23C
		Reel of 2000	TRSF3223CPWR	KIZSC
	SOIC - DW	Tube of 25	TRSF3223IDW	TRSF3223I
	SOIC - DVV	Reel of 2000	TRSF3223IDWR	183532231
−40°C to 85°C	SSOP – DB	Tube of 70	TRSF3223IDB	- RT23I
-40°C 10 65°C	220b - DR	Reel of 2000	TRSF3223IDBR	KIZJI
	TSSOD DW	Tube of 70	TRSF3223IPW	- RT23I
	TSSOP – PW	Reel of 2000	TRSF3223IPWR	N 1231

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

FUNCTION TABLES

Each Driver⁽¹⁾

		INPUTS		OUTPUT	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Х	L	X	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
Н	Н	Н	X	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
Н	L	Н	Yes	L	auto-powerdown enabled
L	L	Н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Each Receiver⁽¹⁾

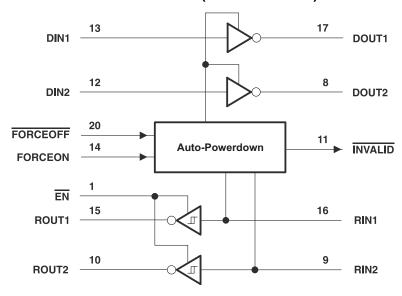
	INPU ⁻	тs	OUTPUT
RIN	EN	VALID RIN RS-232 LEVEL	ROUT
L	L	X	Н
Н	L	X	L
X	Н	X	Z
Open	L	No	Н

(1) H = high level, L = low level, X = irrelevant,
Z = high impedance (off),
Open = input disconnected or connected driver off

TRSF3223



LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range ⁽²⁾		-0.3	6	V
V+	Positive-output supply voltage range (2)	Positive-output supply voltage range (2)		7	V
V-	Negative-output supply voltage range ⁽²⁾		0.3	-7	V
V+ - V-	Supply voltage difference ⁽²⁾			13	V
	land to altere and a	Driver (FORCEOFF, FORCEON, EN)	-0.3	6	V
VI	Input voltage range	Receiver	-25	25	V
V	Outrait valte as season	Driver	-13.23	13.2	V
Vo	Output voltage range	Receiver (INVALID)	-0.3	V _{CC} + 0.3	V
		DB package		70	
θ_{JA}	Package thermal impedance (3)(4)	DW package		58	°C/W
		PW package		83	
T _J	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltages are with respect to network GND.

Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

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Recommended Operating Conditions⁽¹⁾

See Figure 6

				MIN	NOM	MAX	UNIT
	Cumply voltage		$V_{CC} = 3.3 \text{ V}$	3	3.3	3.6	V
	Supply voltage		V _{CC} = 5 V	4.5	5	5.5	V
V	Driver and control	DIN, EN, FORCEOFF, FORCEON	$V_{CC} = 3.3 \text{ V}$	2			V
V _{IH}	high-level input voltage	BIN, EN, FORCEOFF, FORCEON	$V_{CC} = 5 V$	2.4			V
V _{IL}	Driver and control low-level input voltage	DIN, EN, FORCEOFF, FORCEON				0.8	V
\/	Driver and control input voltage	DIN, EN, FORCEOFF, FORCEON		0		5.5	V
VI	Receiver input voltage	nput voltage		-25		25	V
т			TRSF3223C	0		70	°C
IA	Operating free-air temperature	TRSF3223I	-40		85	C	

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER		TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
I _I	Input leakage current	EN, FORCEOFF, FORCEON			±0.01	±1	μΑ
		Auto-powerdown disabled	No load, FORCEOFF, FORCEON at V _{CC}		0.3	1	mA
I _{CC}	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
	Supply surroun	Auto-powerdown enabled	No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

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DRIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	Т	EST CONDITIO	NS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to G	DOUT at $R_L = 3 \text{ k}\Omega$ to GND			5.4		V
V _{OL}	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to Θ	DOUT at $R_L = 3 \text{ k}\Omega$ to GND		- 5	-5.4		V
I _{IH}	High-level input current	$V_I = V_{CC}$	I = V _{CC}			±0.01	±1	μΑ
I _{IL}	Low-level input current	V _I at GND				±0.01	±1	μΑ
	Short-circuit output	V _{CC} = 3.6 V,	V _O = 0 V			±35	±60	A
Ios	current ⁽³⁾	V _{CC} = 5.5 V,	V _O = 0 V			±35	±90	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	V _O = ±2 V		300	10M		Ω
	Output lookage ourrent	FORCEOFF = GND	$V_0 = \pm 12 V$,	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$			±25	
I _{off}	Output leakage current	FUNCEUFF = GND	$V_0 = \pm 10 \text{ V},$	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$			±25	μΑ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V.

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER		TEST CONDITIONS		MIN	TYP ⁽²⁾	MAX	UNIT
		D	C _L = 1000 pF		250			
	Maximum data rate (see Figure 1)	$R_L = 3 \text{ k}\Omega$, One DOUT switching	C _L = 250 pF,	V _{CC} = 3 V to 4.5 V	1000			kbit/s
	(000 1 iguilo 1)	one 2001 emilering	C _L = 1000 pF,	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	1000			
t _{sk(p)}	Pulse skew ⁽³⁾	$C_L = 150 \text{ pF to } 2500 \text{ pF},$	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	See Figure 2		300		ns
SR(tr)	Slew rate, transition region (see Figure 1)	V _{CC} = 3.3 V,	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	C _L = 150 pF to 1000 pF	18		150	V/µs

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (3) Pulse skew is defined as $|t_{PLH}|$ of each channel of the same device.

 ⁽²⁾ All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
(3) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

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RECEIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V _{CC} - 0.6	$V_{CC} - 0.1$		V
V_{OL}	Low-level output voltage	I _{OL} = 1.6 mA			0.4	V
\/	/ _{IT+} Positive-going input threshold voltage	V _{CC} = 3.3 V		1.6	2.4	V
VIT+	Positive-going input tilleshold voltage	V _{CC} = 5 V		1.9	2.4 V	
\/	Negative-going input threshold voltage	V _{CC} = 3.3 V	0.6	1.1	V	
V_{IT-}	Negative-going input threshold voltage	V _{CC} = 5 V	0.8	1.4		V
V_{hys}	Input hysteresis (V _{IT+} - V _{IT-})			0.5		V
I _{off}	Output leakage current	EN = V _{CC}	-	±0.05	±10	μA
ri	Input resistance	$V_1 = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 V \pm 0.3 V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			TYP ⁽²⁾	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF,	See Figure 3		150	ns
t_{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF,	See Figure 3		150	ns
t _{en}	Output enable time	C _L = 150 pF,	$R_L = 3 k\Omega$,	See Figure 4	200	ns
t _{dis}	Output disable time	C _L = 150 pF,	$R_L = 3 k\Omega$,	See Figure 4	200	ns
t _{sk(p}	Pulse skew ⁽³⁾	See Figure 3			50	ns

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3.3 $V \pm 0.3$ V; C1 = 0.047 μ F, C2–C4 = 0.33 μ F at V_{CC} = 5 $V \pm 0.5$ V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (3) Pulse skew is defined as $|t_{PLH}|$ of each channel of the same device.

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AUTO-POWERDOWN SECTION

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TEST (MIN	MAX	UNIT	
V _{T+(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	FORCEOFF = V _{CC}		2.7	V
V _{T-(valid)}	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	FORCEOFF = V _{CC}	-2.7		V
V _{T(invalid)}	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND,	FORCEOFF = V _{CC}	-0.3	0.3	V
V _{OH}	INVALID high-level output voltage	I _{OH} = 1 mA, FORCEOFF = V _{CC}	FORCEON = GND,	V _{CC} - 0.6		V
V _{OL}	INVALID low-level output voltage	I _{OL} = 1.6 mA, FORCEOFF = V _{CC}	FORCEON = GND,		0.4	V

Switching Characteristics

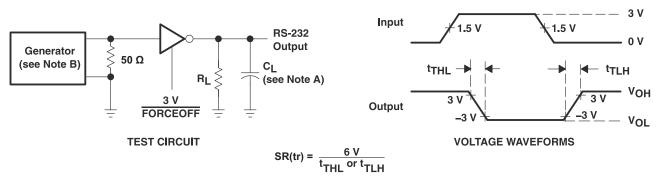
over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TYP ⁽¹⁾	UNIT
t _{valid}	Propagation delay time, low- to high-level output	1	μs
t _{invalid}	Propagation delay time, high- to low-level output	30	μs
t _{en}	Supply enable time	100	μs

⁽¹⁾ All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

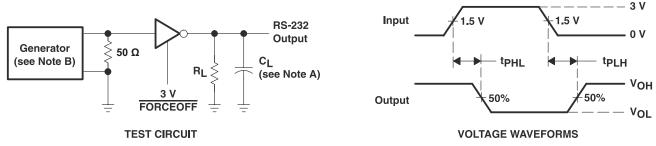


PARAMETER MEASUREMENT INFORMATION



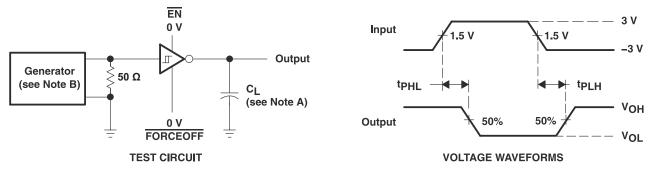
- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbits/s, Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 1. Driver Slew Rate



- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbits/s, $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_t \le 10$ ns.

Figure 2. Driver Pulse Skew

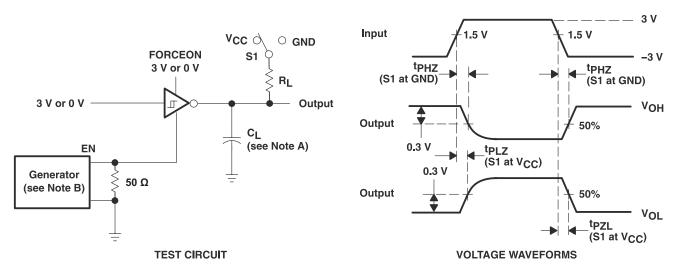


- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times

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PARAMETER MEASUREMENT INFORMATION (continued)

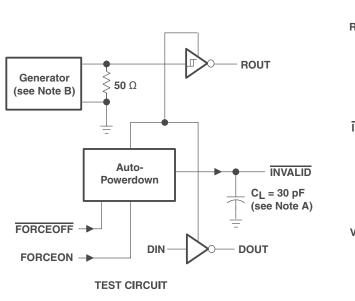


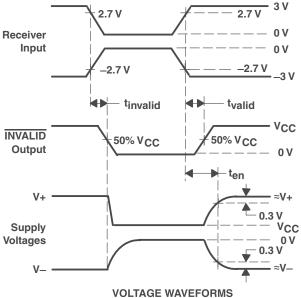
- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

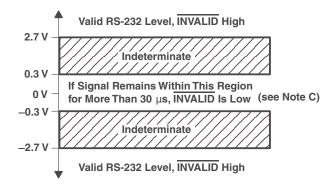
Figure 4. Receiver Enable and Disable Times



PARAMETER MEASUREMENT INFORMATION (continued)





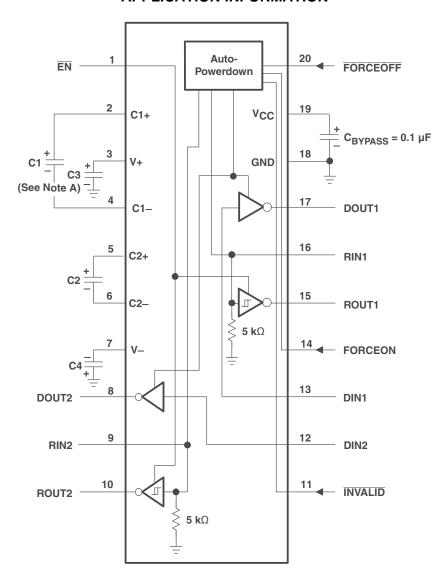


- A. C_L includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 5 kbits/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10 \text{ ns}$, $t_r \le 10 \text{ ns}$.
- C. Auto-powerdown disables drivers and reduces supply current to 1 µA.

Figure 5. INVALID Propagation Delay Times and Supply Enabling Time



APPLICATION INFORMATION



V_{CC} vs CAPACITOR VALUES

VCC	C1	C2, C3, C4
3.3 V ± 0.3 V	0.1 μF	0.1 μF
5 V ± 0.5 V	0.047 μF	0.33 μF
3 V to 5.5 V	0.1 μF	0.47 μF

- A. C3 can be connected to V_{CC} or GND.
- B. Resistor values shown are nominal.

Figure 6. Typical Operating Circuit and Capacitor Values



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TRSF3223CDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223CPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TRSF3223IPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $^{^{(1)}}$ The marketing status values are defined as follows:



PACKAGE OPTION ADDENDUM

26-Sep-2007

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRSF3223CDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
TRSF3223CDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
TRSF3223CPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TRSF3223IDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
TRSF3223IDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
TRSF3223IPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRSF3223CDBR	SSOP	DB	20	2000	346.0	346.0	33.0
TRSF3223CDWR	SOIC	DW	20	2000	346.0	346.0	41.0
TRSF3223CPWR	TSSOP	PW	20	2000	346.0	346.0	33.0
TRSF3223IDBR	SSOP	DB	20	2000	346.0	346.0	33.0
TRSF3223IDWR	SOIC	DW	20	2000	346.0	346.0	41.0
TRSF3223IPWR	TSSOP	PW	20	2000	346.0	346.0	33.0

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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